

JAN2N6298 Information

Heisener.com

Part Number JAN2N6298

Manufacturer Microsemi Corporation

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS PNP DARL 60V 8A TO-66

TO-213AA, TO-66-2 **Package**

For the pricing/inventory/lead time, please contact

Website: https://www.heisener.com For Reference Only

E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









JAN2N6298 Specifications

Manufacturer Part Number	JAN2N6298
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-213AA, TO-66-2
Series	Military, MIL-PRF-19500/540
Transistor Type	PNP - Darlington
Current - Collector (Ic) (Max)	8A
Voltage - Collector Emitter Breakdown (Max)	60V
Vce Saturation (Max) @ Ib, Ic	2V @ 80mA, 8A
Current - Collector Cutoff (Max)	500μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	750 @ 4A, 3V
Power - Max	64W
Frequency - Transition	-
Operating Temperature	-65°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-213AA, TO-66-2
Supplier Device Package	TO-66 (TO-213AA)
	Report errors?

JAN2N6298 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

JAN2N6298 Payment Methods

































If you have any question about JAN2N6298, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com